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FQPF22P10 P-Channel QFET[®] MOSFET -100 V, -13.2 A, 125 mΩ

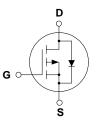
Description

This P-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor[®]'s proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

- 13.2 A, -100 V, $R_{DS(on)}$ =125 m $\Omega(Max.)$ @V_{GS}=-10 V, I_D=-6.6 A
- Low Gate Charge (Typ. 40 nC)
- Low Crss (Typ. 160 pF)
- 100% Avalanche Tested
- 175°C Maximum Junction Temperature Rating





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

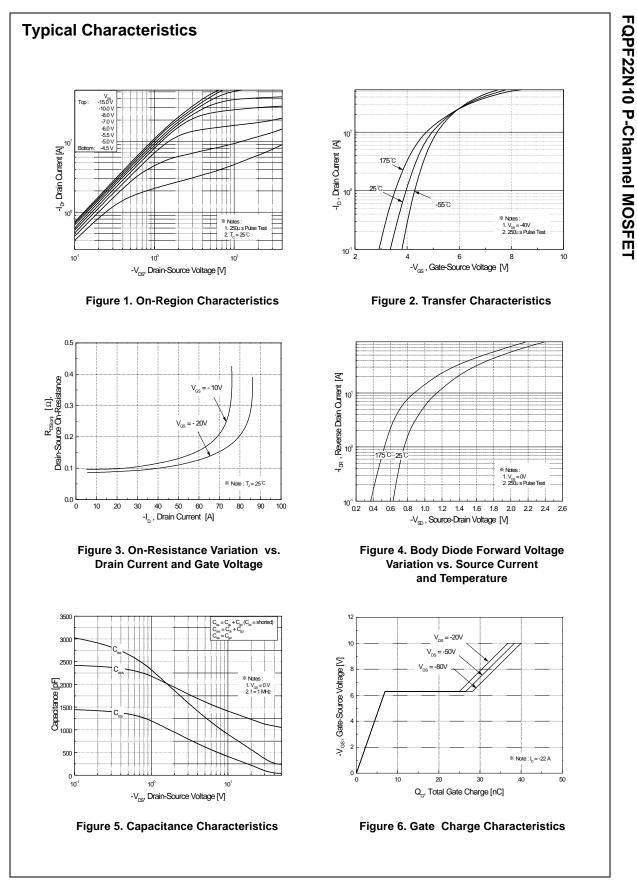
Symbol	Parameter		FQPF22P10	Unit	
V _{DSS}	Drain-Source Voltage		-100	V	
I _D	Drain Current - Continuous ($T_C = 25^\circ$	C)	-13.2	A	
	- Continuous (T _C = 100	°C)	-9.3	A	
I _{DM}	Drain Current - Pulsed	(Note 1)	-52.8	A	
V _{GSS}	Gate-Source Voltage		± 30	V	
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	710	mJ	
AR	Avalanche Current	(Note 1)	-13.2	А	
E _{AR}	Repetitive Avalanche Energy	(Note 1)	4.5	mJ	
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	-6.0	V/ns	
PD	Power Dissipation ($T_C = 25^{\circ}C$)		45	W	
	- Derate above 25°C		0.3	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +175	°C	
ΓL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300	°C	

Thermal Characteristics

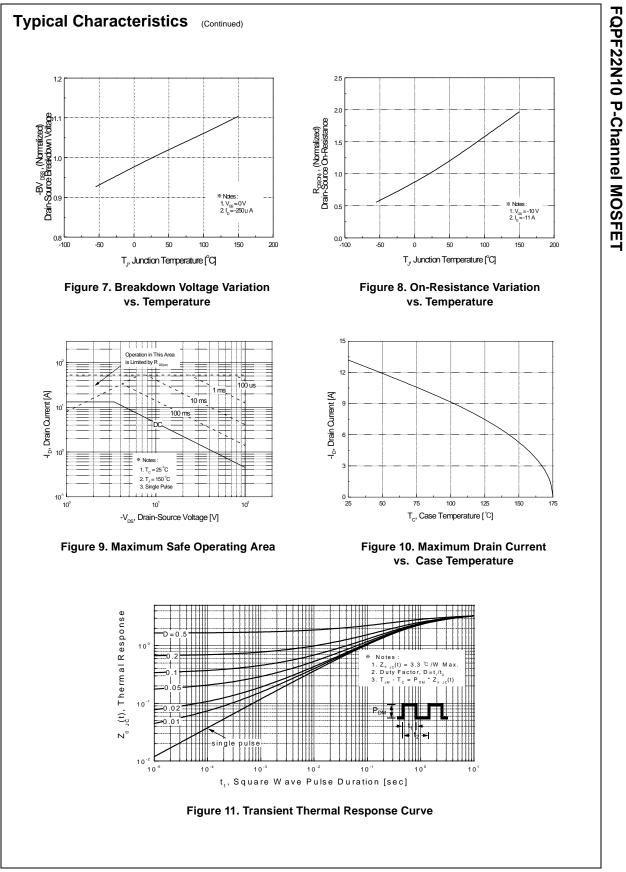
Symbol	Parameter	Тур	Max	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction-to-Case		3.3	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction-to-Ambient		62.5	°C/W

March 2013

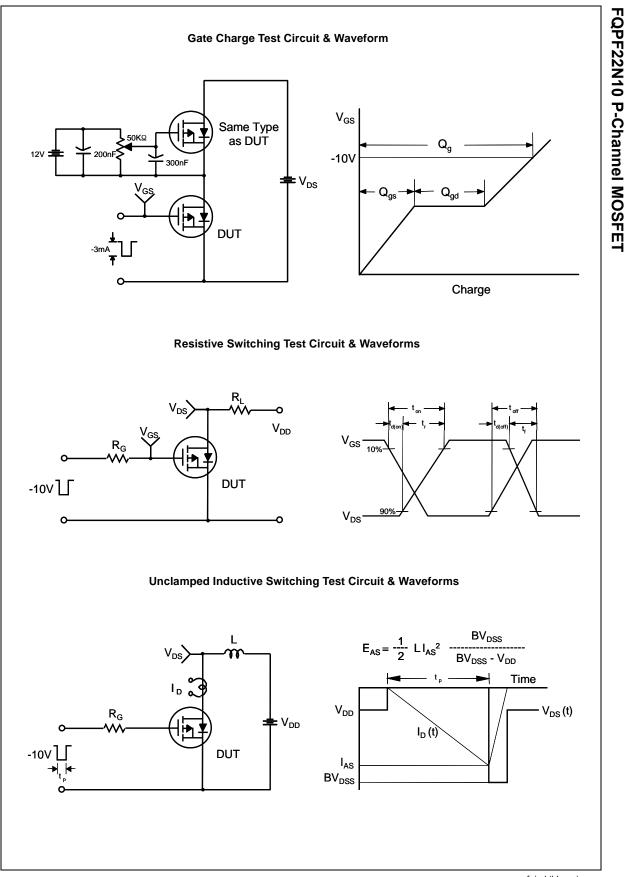
Symbol	Parameter	Test Conditions		Min	Тур	Max	Unit
Off Cha	racteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = -250 μA		-100			V
ΔBV _{DSS} ′ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = -250 \mu$ A, Referenced to 25°C			-0.1		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -100 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$				-1	μA
	-	V _{DS} = -80 V, T _C = 125°C				-10	μΑ
GSSF	Gate-Body Leakage Current, Forward	V_{GS} = -30 V, V_{DS} = 0 V				-100	nA
GSSR	Gate-Body Leakage Current, Reverse	$V_{GS} = 30 \text{ V}, V_{DS} = 0 \text{ V}$				100	nA
On Cha	racteristics						
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$		-2.0		-4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -6.6 \text{ A}$			0.096	0.125	Ω
ĴFS	Forward Transconductance	V _{DS} = -40 V, I _D = -6.6 A	(Note 4)		11		S
Dynam C _{iss}	ic Characteristics				1170	1500	pF
C _{oss}	Output Capacitance	V _{DS} = -25 V, V _{GS} = 0 V, f = 1.0 MHz			460	600	pF
C _{rss}	Reverse Transfer Capacitance				160	200	pF
d(on) r	ng Characteristics Turn-On Delay Time Turn-On Rise Time	$V_{DD} = -50 \text{ V}, \text{ I}_{D} = -22 \text{ A},$		17 170	45 350	ns ns	
		V _{DD} = -50 V, I _D = -22 A,					
d(off)	Turn-Off Delay Time	R _G = 25 Ω (Note 4, 5)		60	130	ns	
f	Turn-Off Fall Time		Note 4, 5)		110	230	ns
ე _g	Total Gate Charge	V _{DS} = -80 V, I _D = -22 A,			40	50	nC
ຊ _{gs}	Gate-Source Charge	$V_{GS} = -10 V$			7.0		nC
ຊ _{gd}	Gate-Drain Charge	(Note 4, 5)			21		nC
	euros Diado Characteristico e	d Movimum Dotingo					
s s	ource Diode Characteristics an Maximum Continuous Drain-Source Dio					-13.2	Α
SM	Maximum Pulsed Drain-Source Diode F					-52.8	A
V _{SD}	Drain-Source Diode Forward Voltage					-4.0	V
rr	Reverse Recovery Time	$V_{GS} = 0 V, I_S = -22 A,$			110		ns
2 _{rr}	Reverse Recovery Charge	dl _F / dt = 100 A/µs	(Note 4)		0.6		μC
L = 6.1mH, I I _{SD} ≤ -22A,	ating : Pulse width limited by maximum junction tempe $_{AS}$ = -13.2A, V _{DD} = -25V, R _G = 25 Ω, Starting T _J = 25° di/dt $\leq 300A/\mu$ s, V _{DD} $\leq BV_{DSS}$, Starting T _J = 25°C Pulse width ≤ 300 µs, Duty cycle $\leq 2\%$						
	ndependent of operating temperature						



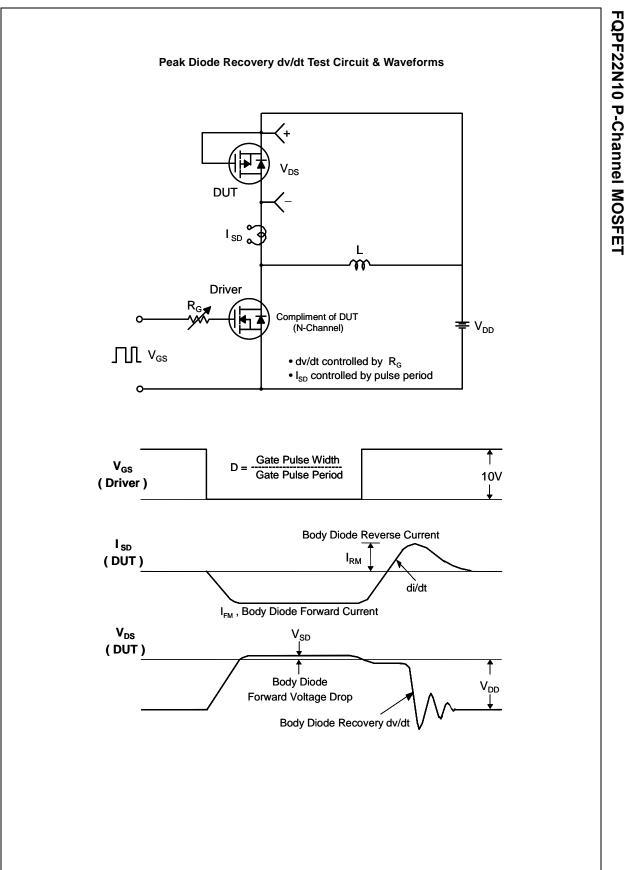
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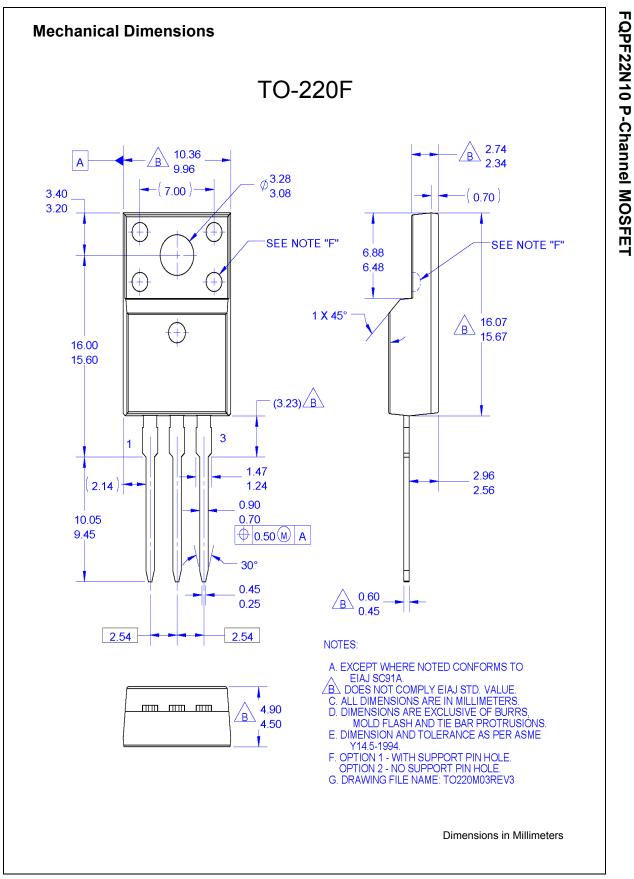
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